



Improved, Quad, SPST Analog Switches

DG444/DG445

General Description

Maxim's redesigned DG444/DG445 analog switches now feature on-resistance matching (4Ω max) between switches and guaranteed on-resistance flatness over the signal range (9Ω max). These low on-resistance switches conduct equally well in either direction. They guarantee low charge injection (10pC max), low power consumption ($35\mu\text{W}$ max), and an electrostatic discharge (ESD) tolerance of 2000V (min) per Method 3015.7. The new design offers lower off-leakage current over temperature (less than 5nA at $+85^\circ\text{C}$).

The DG444/DG445 are quad, single-pole/single-throw (SPST) analog switches. The DG444 has four normally closed switches and the DG445 has four normally open switches. Switching times are less than 250ns for t_{ON} and less than 70ns for t_{OFF} . Operation is from a single +10V to +30V supply, or bipolar $\pm 4.5\text{V}$ to $\pm 20\text{V}$ supplies. Maxim's improved DG444/DG445 continue to be fabricated with a 44V silicon-gate process.

Applications

Sample-and-Hold Circuits	Communication Systems
Test Equipment	Battery-Operated Systems
Heads-Up Displays	PBX, PABX
Guidance and Control Systems	Audio Signal Routing
Military Radios	Modems/Faxes

Rail-to Rail is a registered trademark of Nippon Motorola, Ltd.

New Features

- ◆ Plug-In Upgrades for Industry-Standard DG444/DG445
- ◆ Improved r_{ON} Match Between Channels (4Ω max)
- ◆ Guaranteed $r_{\text{FLAT(ON)}}$ Over Signal Range (9Ω max)
- ◆ Improved Charge Injection (10pC max)
- ◆ Improved Off-Leakage Current Over Temperature ($< 5\text{nA}$ at $+85^\circ\text{C}$)
- ◆ Withstand ESD (2000V min) per Method 3015.7

Existing Features

- ◆ Low $r_{\text{DS(ON)}}$ (85Ω max)
- ◆ Single-Supply Operation +10V to +30V
Bipolar-Supply Operation $\pm 4.5\text{V}$ to $\pm 20\text{V}$
- ◆ Low Power Consumption ($35\mu\text{W}$ max)
- ◆ Rail-to-Rail® Signal Handling
- ◆ TTL/CMOS-Logic Compatible

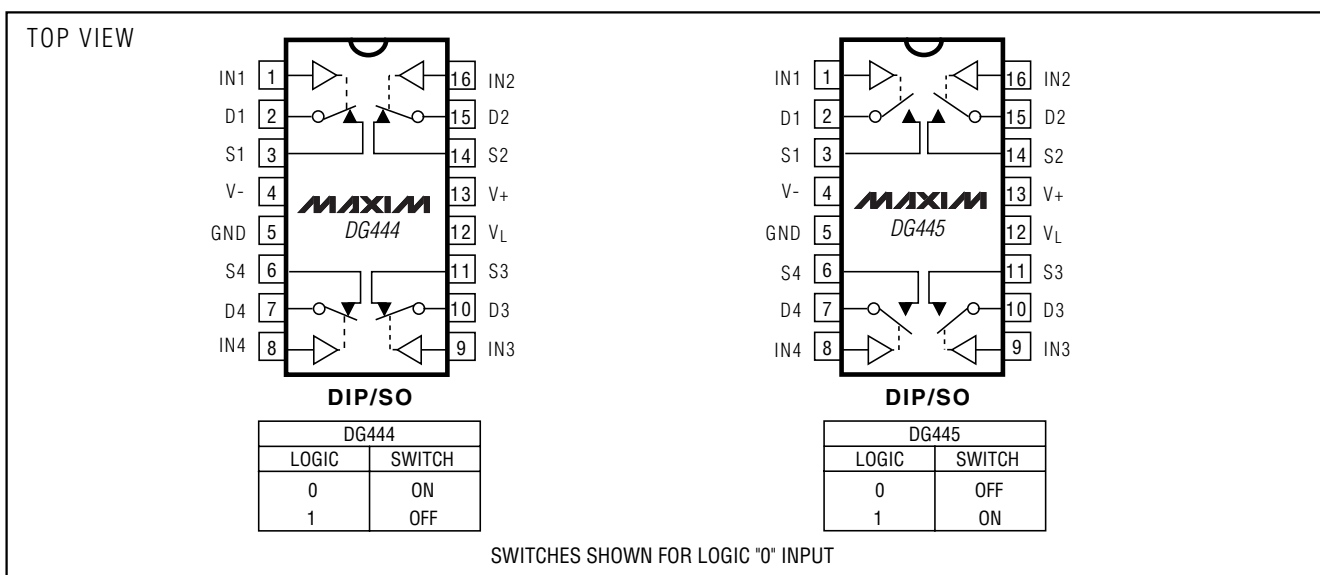
Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
DG444CJ	0°C to $+70^\circ\text{C}$	16 Plastic DIP
DG444CY	0°C to $+70^\circ\text{C}$	16 Narrow SO
DG444C/D	0°C to $+70^\circ\text{C}$	Dice*
DG444DJ	-40°C to $+85^\circ\text{C}$	16 Plastic DIP
DG444DY	-40°C to $+85^\circ\text{C}$	16 Narrow SO

Ordering Information continued at end of data sheet.

*Contact factory for dice specifications.

Pin Configurations/Functional Diagrams/Truth Tables



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ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to V-

V+44V
GND25V
V_L(GND -0.3V) to (V+ +0.3V)
Digital Inputs V_S, V_D (Note 1).....(V- -2V) to (V+ +2V) or 30mA
(whichever occurs first)

Continuous Current (any terminal).....30mA
Peak Current, S or D (pulsed at 1ms, 10% duty cycle max) .100mA

Continuous Power Dissipation (T_A = +70°C)

16-Pin PDIP (derate 10.53mW/°C above +70°C).....842mW
16-Pin Narrow SO (derate 8.70mW/°C above +70°C) ...696mW

Operating Temperature Ranges

DG444C/DG445C0°C to +70°C
DG444D/DG445D-40°C to +85°C

Storage Temperature Range-65°C to +150°C

Lead Temperature (soldering, 10s)+300°C

Note 1: Signals on S, D, or IN exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = 15V, V- = -15V, V_L = 5V, GND = 0, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN TYP MAX (Note 2)			UNITS
SWITCH							
Analog Signal Range	V _{ANALOG}	(Note 3)		-15	15	V	
Drain-Source On-Resistance	r _{DS(ON)}	V ₊ = 13.5V, V ₋ = -13.5V, V _D = ±8.5V, I _S = -10mA	T _A = +25°C	50	85	Ω	
			T _A = T _{MIN} to T _{MAX}	100			
On-Resistance Match Between Channels (Note 4)	Δr _{DS(ON)}	V _D = ±10V, I _S = -10mA	T _A = +25°C	4		Ω	
			T _A = T _{MIN} to T _{MAX}	5			
On-Resistance Flatness (Note 4)	r _{FLAT(ON)}	V _D = ±5V, I _S = -10mA	T _A = +25°C	9		Ω	
			T _A = T _{MIN} to T _{MAX}	15			
Source Leakage Current (Note 5)	I _{S(OFF)}	V ₊ = 16.5V, V ₋ = -16.5V, V _D = ±15.5V, V _S = ∓ 15.5V	T _A = +25°C	-0.50	0.01	0.50	nA
			T _A = T _{MIN} to T _{MAX}	-5	5		
Drain Off-Leakage Current (Note 5)	I _{D(OFF)}	V ₊ = 16.5V, V ₋ = -16.5V, V _D = ±15.5V, V _S = ∓ 15.5V	T _A = +25°C	-0.50	0.01	0.50	nA
			T _A = T _{MIN} to T _{MAX}	-5	5		
Drain On-Leakage Current (Note 5)	I _{D(ON)} or I _{S(ON)}	V ₊ = 16.5V, V ₋ = -16.5V, V _D = ±15.5V, V _S = ±15.5V	T _A = +25°C	-0.50	0.08	0.50	nA
			T _A = T _{MIN} to T _{MAX}	-10	10		
INPUT							
Input Current with Input Voltage High	I _{INH}	V _{IN} = 2.4V, all others = 0.8V		-0.5	-0.00001	0.5	μA
Input Current with Input Voltage Low	I _{INL}	V _{IN} = 0.8V, all others = 2.4V		-0.5	-0.00001	0.5	μA

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ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

(V₊ = 15V, V₋ = -15V, V_L = 5V, GND = 0, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
SWITCH							
Power-Supply Range	V+, V-			±4.5		±20.0	V
Positive Supply Current	I+	All channels on or off, V+ = 16.5V, V- = -16.5V, VIN = 0V or 5V	TA = +25°C	-1	-0.001	1	µA
			TA = TMIN to TMAX	-5		5	
Negative Supply Current	I-	All channels on or off, V+ = 16.5V, V- = -16.5V, VIN = 0V or 5V	TA = +25°C	-1	-0.0001	1	µA
			TA = TMIN to TMAX	-5		5	
Logic Supply Current	IL	All channels on or off, V+ = 16.5V, V- = -16.5V, VIN = 0V or 5V	TA = +25°C	-1	-0.001	1	µA
			TA = TMIN to TMAX	-5		5	
Ground Current	IGND	All channels on or off, V+ = 16.5V, V- = -16.5V, VIN = 0V or 5V	TA = +25°C	-1	-0.0001	1	µA
			TA = TMIN to TMAX	-5		5	
INPUT							
Turn-On Time	ton	VS = ±10V, Figure 2	TA = +25°C		150	250	ns
Turn-Off Time	toff	DG444, VS = ±10V, Figure 2	TA = +25°C		90	120	ns
		DG445, VS = ±10V, Figure 2	TA = +25°C		110	170	ns
Charge Injection (Note 3)	Q	CL = 1nF, VGEN = 0, RGEN = 0Ω, Figure 3	TA = +25°C		5	10	pC
Off-Isolation Rejection Ratio (Note 6)	OIRR	RL = 50Ω, CL = 5pF, f = 1MHz, Figure 4	TA = +25°C		60		dB
Crosstalk (Note 7)		RL -50Ω, CL = 5pF, f = 1MHz, Figure 5	TA = +25°C		100		dB
Source Off-Capacitance	CS(OFF)	f = 1MHz, Figure 6	TA = +25°C		4		pF
Drain Off-Capacitance	CD(OFF)	f = 1MHz, Figure 6	TA = +25°C		4		pF
Source On-Capacitance	CS(ON)	f = 1MHz, Figure 7	TA = +25°C		16		pF
Drain On-Capacitance	CD(ON)	f = 1MHz, Figure 7	TA = +25°C		16		pF

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ELECTRICAL CHARACTERISTICS—Single Supply

($V_+ = 12\text{V}$, $V_- = 0$, $V_L = 5\text{V}$, $\text{GND} = 0$, $V_{\text{INH}} = 2.4\text{V}$, $V_{\text{INL}} = 0.8\text{V}$, $T_A = T_{\text{MIN}}$ to T_{MAX} , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
SWITCH							
Analog Signal Range	V _{ANALOG}	(Note 3)		0		12	V
Drain-Source On-Resistance	r _{DS(ON)}	V ₊ = 10.8V; V _L = 5.25V; V _D = 3V, 8V; I _S = -10mA	T _A = +25°C	100	160	Ω	
			T _A = T _{MIN} to T _{MAX}		200		
SUPPLY							
Power-Supply Range	V ₊ , V ₋			10.8		24.0	V
Power-Supply Current	I ₊	All channels on or off, V _{IN} = 0V or 5V	T _A = +25°C	-1	0.001	1	μA
			T _A = T _{MIN} to T _{MAX}	-5		5	
Negative Supply Current	I ₋	All channels on or off, V _{IN} = 0V or 5V	T _A = +25°C	-1	-0.0001	1	μA
			T _A = T _{MIN} to T _{MAX}	-5		5	
Logic Supply Current	I _L	All channels on or off, V _{IN} = 0V or 5V	T _A = +25°C	-1	0.001	1	μA
			T _A = T _{MIN} to T _{MAX}	-5		5	
Ground Current	I _{GND}	All channels on or off, V _{IN} = 0V or 5V	T _A = +25°C	-1	-0.0001	1	μA
			T _A = T _{MIN} to T _{MAX}	-5		5	
DYNAMIC							
Turn-On Time	t _{ON}	V _S = 8V, Figure 2	T _A = +25°C		300	400	ns
Turn-Off Time	t _{OFF}	V _S = 8V, Figure 2	T _A = +25°C		60	200	ns
Charge Injection (Note 3)	Q	C _L = 1nF, V _{GEN} = 0, R _{GEN} = 0Ω, Figure 3	T _A = +25°C		5	10	pC

Note 2: Typical values are for **design aid only**, are not guaranteed, and are not subject to production testing. The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

Note 3: Guaranteed by design.

Note 4: On-resistance match between channels and flatness are guaranteed only with bipolar-supply operation. Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured at the extremes of the specified analog signal range.

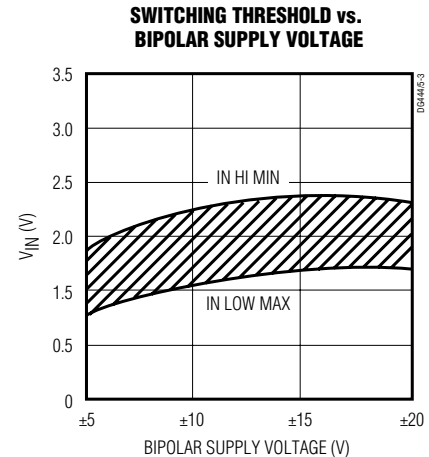
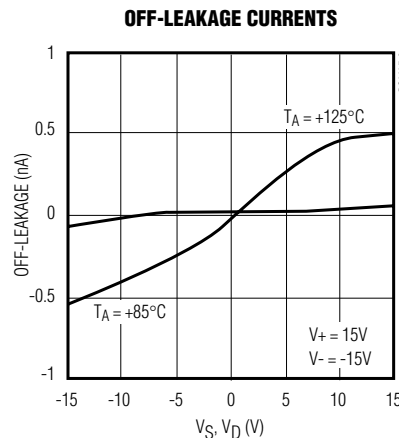
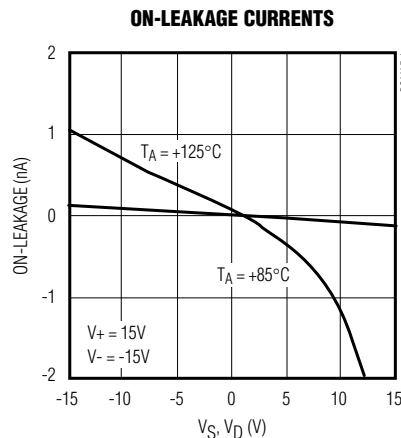
Note 5: Leakage parameters $I_{\text{S(OFF)}}$, $I_{\text{D(OFF)}}$, $I_{\text{D(ON)}}$, and $I_{\text{S(ON)}}$ are 100% tested at the maximum rated hot temperature and guaranteed at $+25^\circ\text{C}$.

Note 6: Off-Isolation Rejection Ratio = $20\log(V_D/V_S)$, V_D = output, V_S = input to off switch.

Note 7: Between any two switches.

Typical Operating Characteristics

($T_A = +25^\circ\text{C}$, unless otherwise noted.)



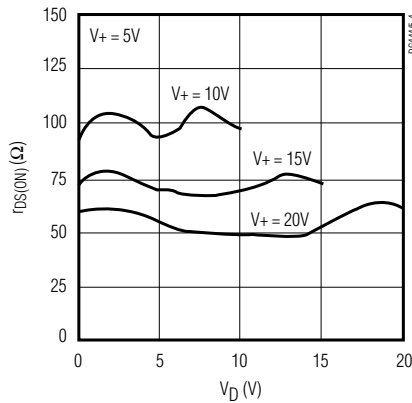
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Typical Operating Characteristics

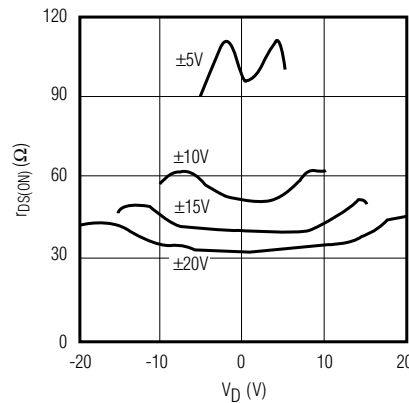
($T_A = +25^\circ\text{C}$, unless otherwise noted.)

DG4444/DG4445

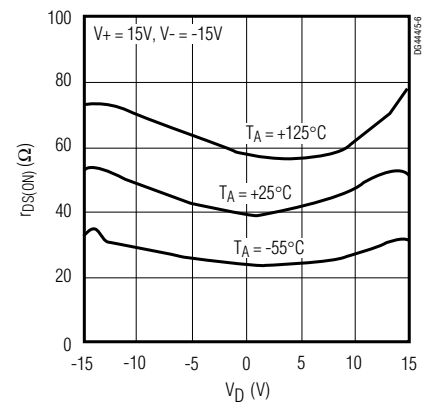
ON-RESISTANCE vs. V_D AND UNIPOLAR-SUPPLY VOLTAGE



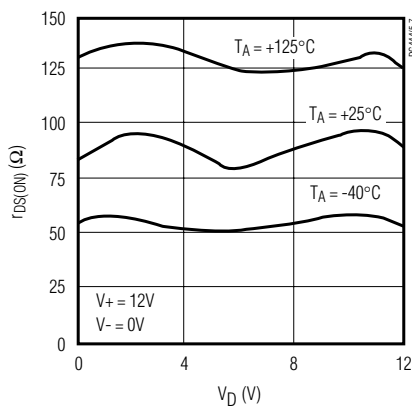
ON-RESISTANCE vs. V_D AND BIPOLAR-SUPPLY VOLTAGE



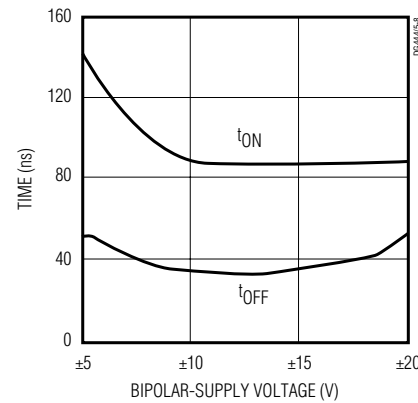
ON-RESISTANCE vs. V_D , BIPOLAR-SUPPLY VOLTAGE AND TEMPERATURE



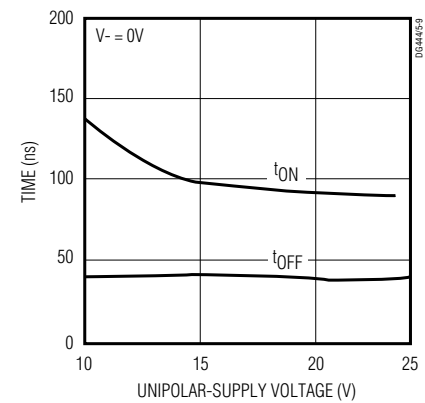
ON-RESISTANCE vs. V_D , UNIPOLAR-SUPPLY VOLTAGE AND TEMPERATURE



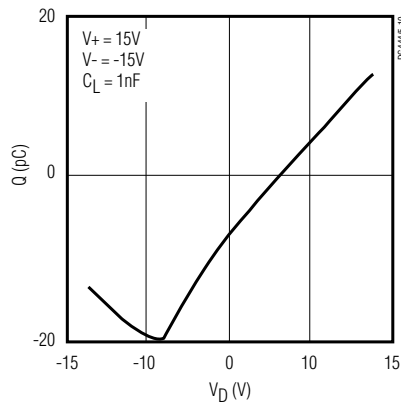
SWITCHING TIME vs. BIPOLAR-SUPPLY VOLTAGE



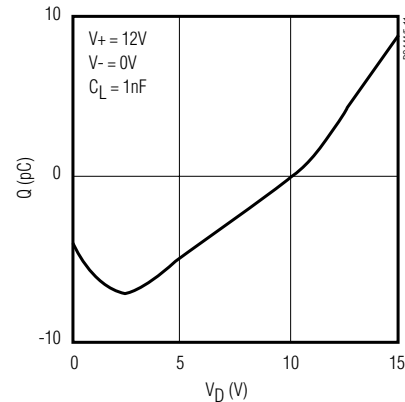
SWITCHING TIME vs. UNIPOLAR-SUPPLY VOLTAGE



CHARGE INJECTION vs. V_D VOLTAGE



CHARGE INJECTION vs. V_D VOLTAGE



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Pin Description

PIN	NAME	FUNCTION
1, 16, 9, 8	IN1-IN4	Logic Control Inputs
2, 15, 10, 7	D1-D4	Drain Outputs
3, 14, 11, 6	S1-S4	Source Outputs
4	V-	Negative Supply-Voltage Input
5	GND	Ground
12	V _L	Logic Supply-Voltage Input
13	V+	Positive Supply-Voltage Input—connected to substrate

Applications Information

General Operation

- Switches are open when power is off.
- IN, D, and S should not exceed V+ or V-, even with the power off.
- Switch leakage is from each analog switch terminal to V+ or V-, not to other switch terminals.

Operation with Supply Voltages Other than ±15V

Using supply voltages other than ±15V will reduce the analog signal range. The DG444/DG445 switches operate with ±4.5V to ±20V bipolar supplies or with a +10V to +30V single supply; connect V- to 0V when operating with a single supply. Also, all device types can operate with unbalanced supplies such as +24V and -5V. V_L must be connected to +5V to be TTL compatible, or to V+ for CMOS-logic level inputs. The *Typical Operating*

Characteristics graphs show typical on-resistance with ±20V, ±15V, ±10V, and ±5V supplies. (Switching times increase by a factor of two or more for operation at ±5V.)

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, followed by V_L, V-, and logic inputs. If power-supply sequencing is not possible, add two small, external signal diodes in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to 1V below V+ and 1V above V-, but low switch resistance and low leakage characteristics are unaffected. Device operation is unchanged, and the difference between V+ and V- should not exceed +44V.

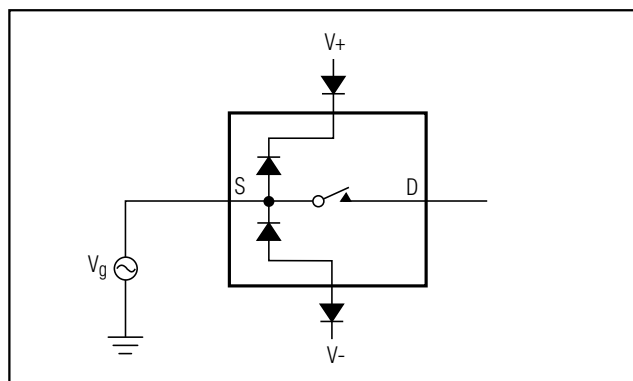


Figure 1. Overvoltage Protection Using External Blocking Diodes

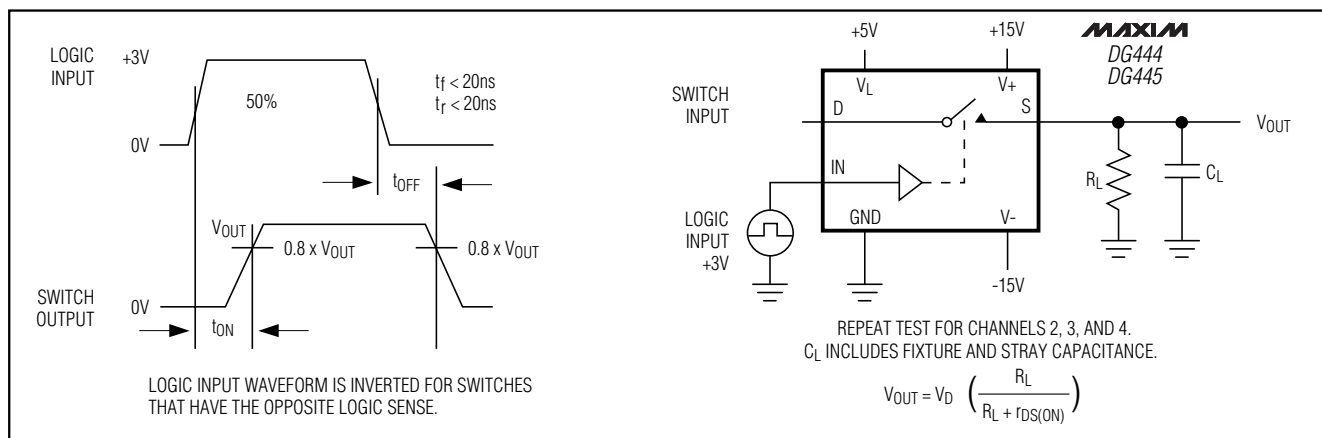


Figure 2. Switching Time

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DG444/DG445

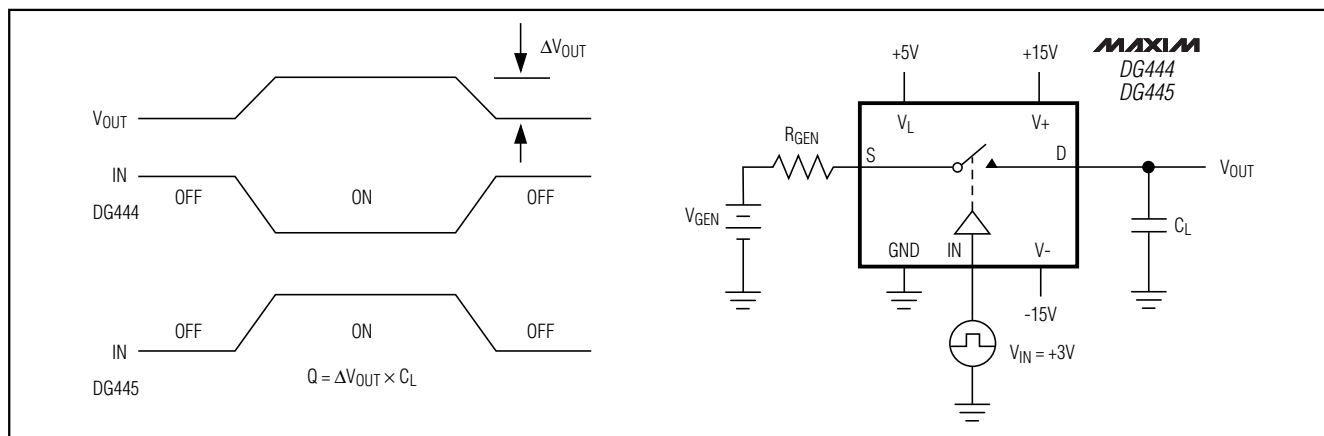


Figure 3. Charge Injection

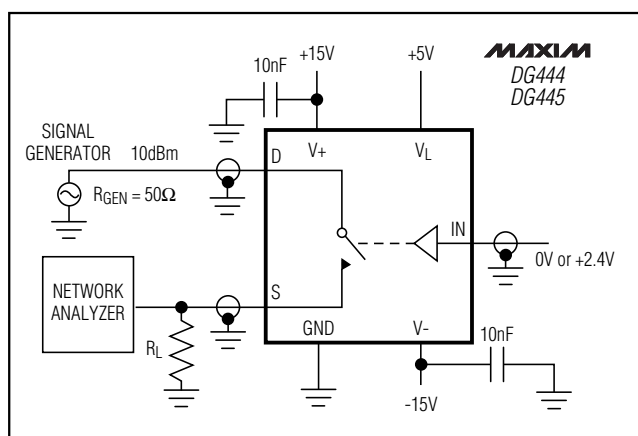


Figure 4. Off-Isolation Rejection Ratio

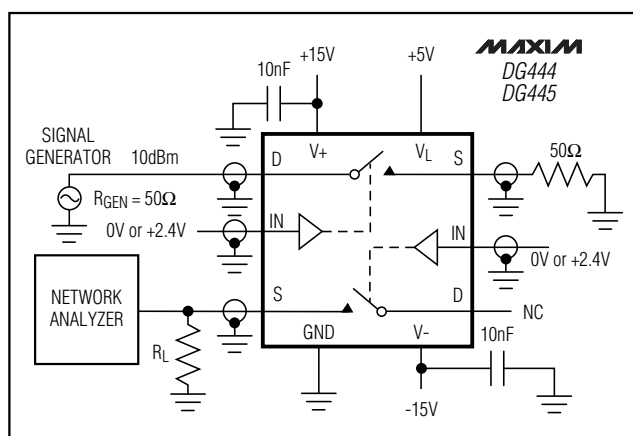


Figure 5. Crosstalk

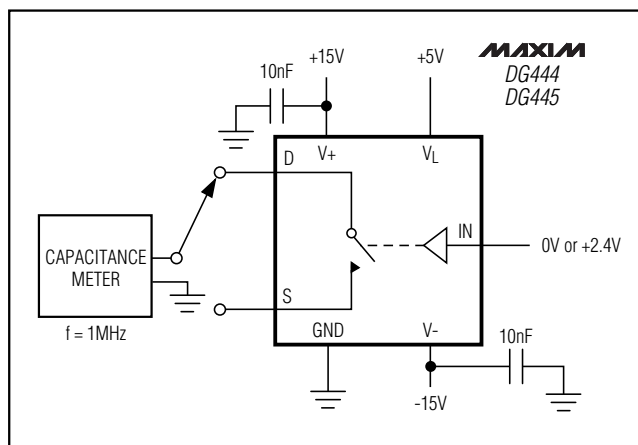


Figure 6. Source/Drain Off-Capacitance

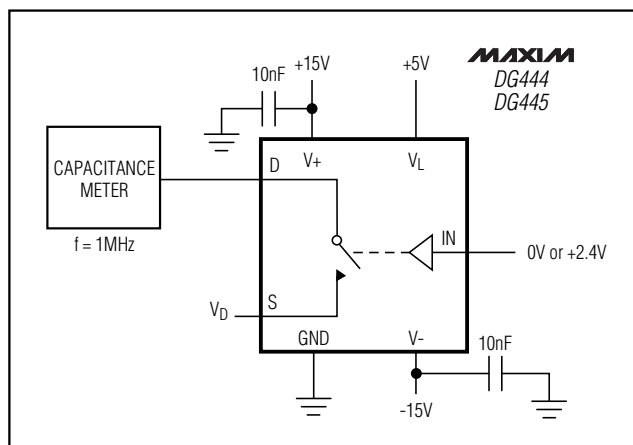


Figure 7. Source/Drain On-Capacitance

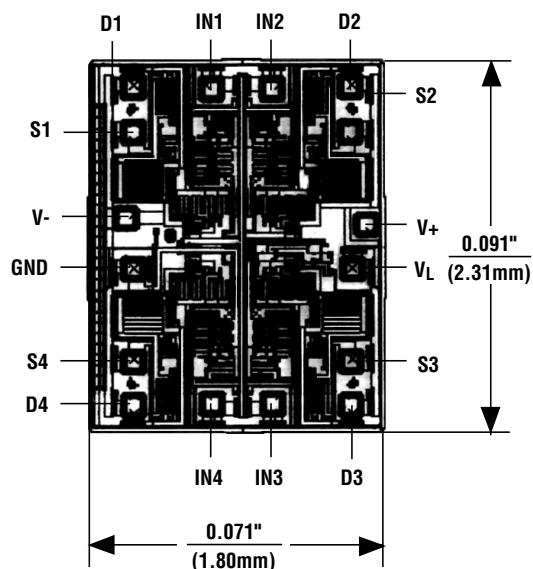
Improved, Quad, SPST Analog Switches

Ordering Information (continued)

PART	TEMP. RANGE	PIN-PACKAGE
DG445CJ	0°C to +70°C	16 Plastic DIP
DG445CY	0°C to +70°C	16 Narrow SO
DG445C/D	0°C to +70°C	Dice*
DG445DJ	-40°C to +85°C	16 Plastic DIP
DG445DY	-40°C to +85°C	16 Narrow SO

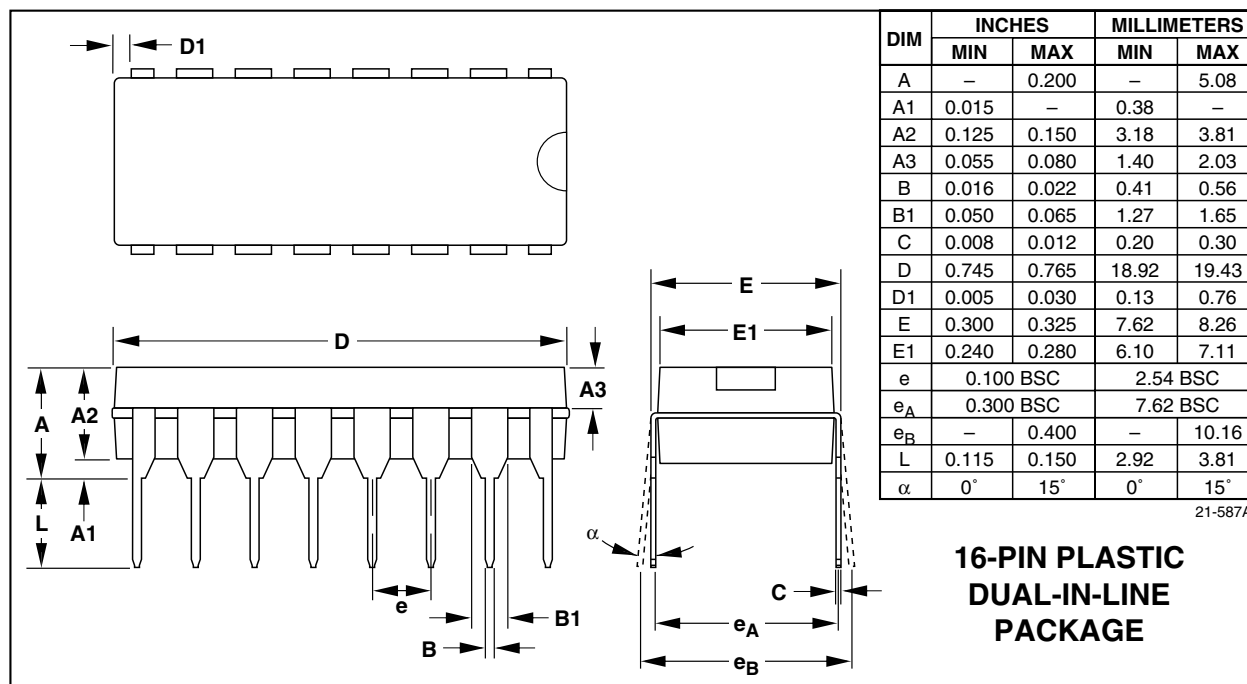
*Contact factory for dice specifications.

Chip Topography



TRANSISTOR COUNT: 126
SUBSTRATE CONNECTED TO V+

Package Information



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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